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Understanding **Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	57
Number of Gates	3000
Voltage - Supply	3V ~ 3.6V, 4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	68-LCC (J-Lead)
Supplier Device Package	68-PLCC (24.23x24.23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a40mx02-fpl68

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3 40MX and 42MX FPGAs

3.1 General Description

Microsemi's 40MX and 42MX families offer a cost-effective design solution at 5V. The MX devices are single-chip solutions and provide high performance while shortening the system design and development cycle. MX devices can integrate and consolidate logic implemented in multiple PALs, CPLDs, and FPGAs. Example applications include high-speed controllers and address decoding, peripheral bus interfaces, DSP, and co-processor functions.

The MX device architecture is based on Microsemi's patented antifuse technology implemented in a 0.45 μ m triple-metal CMOS process. With capacities ranging from 3,000 to 54,000 system gates, the MX devices provide performance up to 250 MHz, are live on power-up and have one-fifth the standby power consumption of comparable FPGAs. MX FPGAs provide up to 202 user I/Os and are available in a wide variety of packages and speed grades.

A42MX24 and A42MX36 devices also feature multiPlex I/Os, which support mixed-voltage systems, enable programmable PCI, deliver high-performance operation at both 5.0V and 3.3V, and provide a low-power mode. The devices are fully compliant with the PCI local bus specification (version 2.1). They deliver 200 MHz on-chip operation and 6.1 ns clock-to-output performance.

The 42MX24 and 42MX36 devices include system-level features such as IEEE Standard 1149.1 (JTAG) Boundary Scan Testing and fast wide-decode modules. In addition, the A42MX36 device offers dual-port SRAM for implementing fast FIFOs, LIFOs, and temporary data storage. The storage elements can efficiently address applications requiring wide data path manipulation and can perform transformation functions such as those required for telecommunications, networking, and DSP.

All MX devices are fully tested over automotive and military temperature ranges. In addition, the largest member of the family, the A42MX36, is available in both CQ208 and CQ256 ceramic packages screened to MIL-STD-883 levels. For easy prototyping and conversion from plastic to ceramic, the CQ208 and PQ208 devices are pin-compatible.

3.2 MX Architectural Overview

The MX devices are composed of fine-grained building blocks that enable fast, efficient logic designs. All devices within these families are composed of logic modules, I/O modules, routing resources and clock networks, which are the building blocks for fast logic designs. In addition, the A42MX36 device contains embedded dual-port SRAM modules, which are optimized for high-speed data path functions such as FIFOs, LIFOs and scratch pad memory. A42MX24 and A42MX36 also contain wide-decode modules.

3.2.1 Logic Modules

The 40MX logic module is an eight-input, one-output logic circuit designed to implement a wide range of logic functions with efficient use of interconnect routing resources.(see the following figure).

The logic module can implement the four basic logic functions (NAND, AND, OR and NOR) in gates of two, three, or four inputs. The logic module can also implement a variety of D-latches, exclusivity functions, AND-ORs and OR-ANDs. No dedicated hard-wired latches or flip-flops are required in the array; latches and flip-flops can be constructed from logic modules whenever required in the application.

Silicon Sculptor programs devices independently to achieve the fastest programming times possible. After being programmed, each fuse is verified to insure that it has been programmed correctly. Furthermore, at the end of programming, there are integrity tests that are run to ensure no extra fuses have been programmed. Not only does it test fuses (both programmed and non-programmed), Silicon Sculptor also allows self-test to verify its own hardware extensively.

The procedure for programming an MX device using Silicon Sculptor is as follows:

1. Load the *.AFM file
2. Select the device to be programmed
3. Begin programming

When the design is ready to go to production, Microsemi offers device volume-programming services either through distribution partners or via In-House Programming from the factory.

For more details on programming MX devices, see the *AC225: Programming Antifuse Devices* application note and the *Silicon Sculptor 3 Programmers User Guide*.

3.3.4 Power Supply

MX devices are designed to operate in both 5.0V and 3.3V environments. In particular, 42MX devices can operate in mixed 5.0 V/3.3 V systems. The following table describes the voltage support of MX devices.

Table 6 • Voltage Support of MX Devices

Device	VCC	VCCA	VCCI	Maximum Input Tolerance	Nominal Output Voltage
40MX	5.0 V	—	—	5.5 V	5.0 V
	3.3 V	—	—	3.6 V	3.3 V
42MX	—	5.0 V	5.0 V	5.5 V	5.0 V
	—	3.3 V	3.3 V	3.6 V	3.3 V
	—	5.0 V	3.3 V	5.5 V	3.3 V

For A42MX24 and A42MX36 devices the VCCA supply has to be monotonic during power up in order for the POR to issue reset to the JTAG state machine correctly. For more information, see the *AC291: 42MX Family Devices Power-Up Behavior*.

3.3.5 Power-Up/Down in Mixed-Voltage Mode

When powering up 42MX in mixed voltage mode (VCCA = 5.0 V and VCCI = 3.3 V), VCCA must be greater than or equal to VCCI throughout the power-up sequence. If VCCI exceeds VCCA during power-up, one of two things will happen:

- The input protection diode on the I/Os will be forward biased
- The I/Os will be at logical High

In either case, ICC rises to high levels. For power-down, any sequence with VCCA and VCCI can be implemented.

3.3.6 Transient Current

Due to the simultaneous random logic switching activity during power-up, a transient current may appear on the core supply (VCC). Customers must use a regulator for the VCC supply that can source a minimum of 100 mA for transient current during power-up. Failure to provide enough power can prevent the system from powering up properly and result in functional failure. However, there are no reliability concerns, since transient current is distributed across the die instead of confined to a localized spot.

Since the transient current is not due to I/O switching, its value and duration are independent of the VCCI.

Each I/O cell has three boundary-scan register cells, each with a serial-in, serial-out, parallel-in, and parallel-out pin. The serial pins are used to serially connect all the boundary-scan register cells in a device into a boundary-scan register chain, which starts at the TDI pin and ends at the TDO pin. The parallel ports are connected to the internal core logic tile and the input, output and control ports of an I/O buffer to capture and load data into the register to control or observe the logic state of each I/O.

Figure 14 • 42MX IEEE 1149.1 Boundary Scan Circuitry

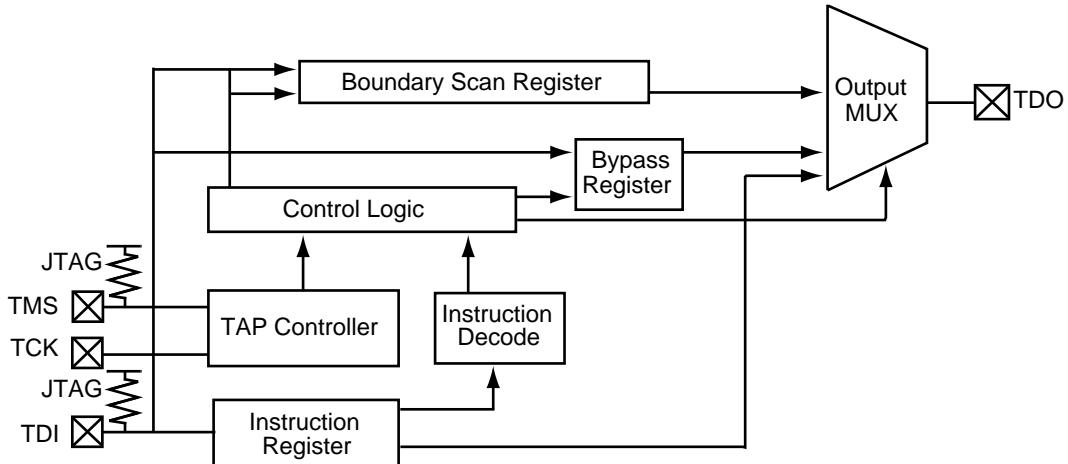


Table 9 • Test Access Port Descriptions

Port	Description
TMS (Test Mode Select)	Serial input for the test logic control bits. Data is captured on the rising edge of the test logic clock (TCK).
TCK (Test Clock Input)	Dedicated test logic clock used serially to shift test instruction, test data, and control inputs on the rising edge of the clock, and serially to shift the output data on the falling edge of the clock. The maximum clock frequency for TCK is 20 MHz.
TDI (Test Data Input)	Serial input for instruction and test data. Data is captured on the rising edge of the test logic clock.
TDO (Test Data Output)	Serial output for test instruction and data from the test logic. TDO is set to an Inactive Drive state (high impedance) when data scanning is not in progress.

Table 10 • Supported BST Public Instructions

Instruction	IR Code (IR2.IR0)	Instruction Type	Description
EXTEST	000	Mandatory	Allows the external circuitry and board-level interconnections to be tested by forcing a test pattern at the output pins and capturing test results at the input pins.
SAMPLE/PRELOAD	001	Mandatory	Allows a snapshot of the signals at the device pins to be captured and examined during operation
HIGH Z	101	Optional	Tristates all I/Os to allow external signals to drive pins. See the IEEE Standard 1149.1 specification.
CLAMP	110	Optional	Allows state of signals driven from component pins to be determined from the Boundary-Scan Register. See the IEEE Standard 1149.1 specification for details.
BYPASS	111	Mandatory	Enables the bypass register between the TDI and TDO pins. The test data passes through the selected device to adjacent devices in the test chain.

3.9.1 Mixed 5.0V/3.3V Electrical Specifications

Table 22 • Mixed 5.0V/3.3V Electrical Specifications

Symbol	Parameter	Commercial		Commercial –F		Industrial		Military		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
VOH ¹	IOH = -10 mA	2.4		2.4				2.4		V
	IOH = -4 mA					2.4		2.4		V
VOL ¹	IOL = 10 mA	0.5		0.5				0.4		V
	IOL = 6 mA					0.4		0.4		V
VIL		-0.3	0.8	-0.3	0.8	-0.3	0.8	-0.3	0.8	V
VIH ²		2.0	VCCA + 0.3	2.0	VCCA + 0.3	2.0	VCCA + 0.3	2.0	VCCA + 0.3	V
IL	VIN = 0.5 V	-10		-10		-10		-10		µA
IH	VIN = 2.7 V	-10		-10		-10		-10		µA
Input Transition Time, T _R and T _F		500		500		500		500		ns
C _{IO}	I/O Capacitance	10		10		10		10		pF
Standby Current, ICC ³	A42MX09	5		25		25		25		mA
	A42MX16	6		25		25		25		mA
	A42MX24, A42MX36	20		25		25		25		mA
Low Power Mode Standby Current		0.5		ICC – 5.0		ICC – 5.0		ICC – 5.0		mA
IIO I/O source sink	Can be derived from the <i>IBIS model</i> (http://www.microsemi.com/soc/techdocs/models/ibis.html) current									

1. Only one output tested at a time. VCCI = min.

2. VIH(Min) is 2.4V for A42MX36 family. This applies only to VCCI of 5V and is not applicable to VCCI of 3.3V

3. All outputs unloaded. All inputs = VCCI or GND

3.9.2 Output Drive Characteristics for 5.0 V PCI Signaling

MX PCI device I/O drivers were designed specifically for high-performance PCI systems. Figure 16, page 28 shows the typical output drive characteristics of the MX devices. MX output drivers are compliant with the PCI Local Bus Specification.

Table 23 • DC Specification (5.0 V PCI Signaling)¹

Symbol	Parameter	PCI		MX		Units	
		Condition	Min.	Max.	Min.		
VCCI	Supply Voltage for I/Os		4.75	5.25	4.75	5.25 ²	V
VIH ³	Input High Voltage		2.0	VCC + 0.5	2.0	VCCI + 0.3	V
VIL	Input Low Voltage		-0.5	0.8	-0.3	0.8	V
IIH	Input High Leakage Current	VIN = 2.7 V		70	—	10	µA
IIL	Input Low Leakage Current	VIN=0.5 V		-70	—	-10	µA
VOH	Output High Voltage	IOUT = -2 mA IOUT = -6 mA	2.4		3.84		V
VOL	Output Low Voltage	IOUT = 3 mA, 6 mA	0.55		—	0.33	V

approximately a 3 ns to a 6 ns delay, which is represented statistically in higher fanout (FO=8) routing delays in the data sheet specifications section, shown in Table 34, page 41.

3.11.3 Timing Derating

MX devices are manufactured with a CMOS process. Therefore, device performance varies according to temperature, voltage, and process changes. Minimum timing parameters reflect maximum operating voltage, minimum operating temperature and best-case processing. Maximum timing parameters reflect minimum operating voltage, maximum operating temperature and worst-case processing.

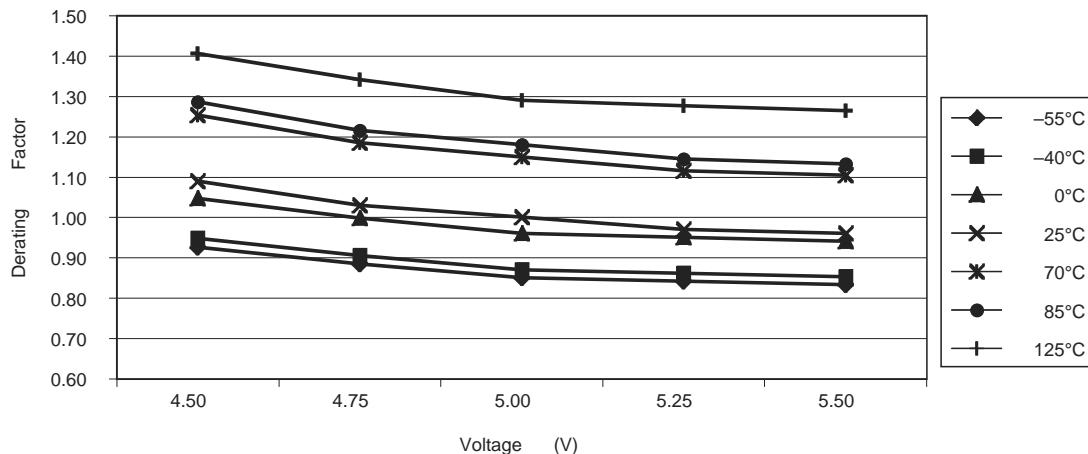
3.11.4 Temperature and Voltage Derating Factors

The following tables and figures show temperature and voltage derating factors for 40MX and 42MX FPGAs.

Table 28 • 42MX Temperature and Voltage Derating Factors (Normalized to $T_J = 25^\circ\text{C}$, $VCCA = 5.0 \text{ V}$)

Temperature								
42MX Voltage	-55°C	-40°C	0°C	25°C	70°C	85°C	125°C	
4.50	0.93	0.95	1.05	1.09	1.25	1.29	1.41	
4.75	0.88	0.90	1.00	1.03	1.18	1.22	1.34	
5.00	0.85	0.87	0.96	1.00	1.15	1.18	1.29	
5.25	0.84	0.86	0.95	0.97	1.12	1.14	1.28	
5.50	0.83	0.85	0.94	0.96	1.10	1.13	1.26	

Figure 34 • 42MX Junction Temperature and Voltage Derating Curves (Normalized to $T_J = 25^\circ\text{C}$, $VCCA = 5.0 \text{ V}$)



Note: This derating factor applies to all routing and propagation delays

Table 29 • 40MX Temperature and Voltage Derating Factors (Normalized to $T_J = 25^\circ\text{C}$, $VCC = 5.0 \text{ V}$)

Temperature								
40MX Voltage	-55°C	-40°C	0°C	25°C	70°C	85°C	125°C	
4.50	0.89	0.93	1.02	1.09	1.25	1.31	1.45	
4.75	0.84	0.88	0.97	1.03	1.18	1.24	1.37	
5.00	0.82	0.85	0.94	1.00	1.15	1.20	1.33	
5.25	0.80	0.82	0.91	0.97	1.12	1.16	1.29	
5.50	0.79	0.82	0.90	0.96	1.10	1.15	1.28	

Table 35 • A40MX02 Timing Characteristics (Nominal 3.3 V Operation) (continued)
(Worst-Case Commercial Conditions, VCC = 3.0 V, T_J = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
CMOS Output Module Timing⁴											
t _{DH}	Data-to-Pad HIGH	5.5	6.4	7.2	8.5	11.9	ns				
t _{DHL}	Data-to-Pad LOW	4.8	5.5	6.2	7.3	10.2	ns				
t _{ENZH}	Enable Pad Z to HIGH	4.7	5.5	6.2	7.3	10.2	ns				
t _{ENZL}	Enable Pad Z to LOW	6.8	7.9	8.9	10.5	14.7	ns				
t _{ENHZ}	Enable Pad HIGH to Z	11.1	12.8	14.5	17.1	23.9	ns				
t _{ENLZ}	Enable Pad LOW to Z	8.2	9.5	10.7	12.6	17.7	ns				
d _{TLH}	Delta LOW to HIGH	0.05	0.05	0.06	0.07	0.10	ns/pF				
d _{THL}	Delta HIGH to LOW	0.03	0.03	0.04	0.04	0.06	ns/pF				

1. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.
2. Set-up times assume fanout of 3. Further testing information can be obtained from the Timer utility.
3. The hold time for the DFME1A macro may be greater than 0 ns. Use the Timer tool from the Designer software to check the hold time for this macro
4. Delays based on 35 pF loading

Table 36 • A40MX04 Timing Characteristics (Nominal 5.0 V Operation) (Worst-Case Commercial Conditions, VCC = 4.75 V, T_J = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Propagation Delays											
t _{PD1}	Single Module	1.2	1.4	1.6	1.9	2.7	ns				
t _{PD2}	Dual-Module Macros	2.3	3.1	3.5	4.1	5.7	ns				
t _{CO}	Sequential Clock-to-Q	1.2	1.4	1.6	1.9	2.7	ns				
t _{GO}	Latch G-to-Q	1.2	1.4	1.6	1.9	2.7	ns				
t _{RS}	Flip-Flop (Latch) Reset-to-Q	1.2	1.4	1.6	1.9	2.7	ns				
Logic Module Predicted Routing Delays¹											
t _{RD1}	FO = 1 Routing Delay	1.2	1.6	1.8	2.1	3.0	ns				
t _{RD2}	FO = 2 Routing Delay	1.9	2.2	2.5	2.9	4.1	ns				
t _{RD3}	FO = 3 Routing Delay	2.4	2.8	3.2	3.7	5.2	ns				
t _{RD4}	FO = 4 Routing Delay	2.9	3.4	3.9	4.5	6.3	ns				
t _{RD8}	FO = 8 Routing Delay	5.0	5.8	6.6	7.8	10.9	ns				
Logic Module Sequential Timing²											
t _{SUD}	Flip-Flop (Latch) Data Input Set-Up	3.1	3.5	4.0	4.7	6.6	ns				
t _{HD³}	Flip-Flop (Latch) Data Input Hold	0.0	0.0	0.0	0.0	0.0	ns				
t _{SUENA}	Flip-Flop (Latch) Enable Set-Up	3.1	3.5	4.0	4.7	6.6	ns				

Table 37 • A40MX04 Timing Characteristics (Nominal 3.3 V Operation) (continued)(Worst-Case Commercial Conditions, VCC = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t _{WCLKA} Flip-Flop (Latch) Clock Active Pulse Width	4.6		5.3		5.6		7.0		9.8		ns
t _{WASYN} Flip-Flop (Latch) Asynchronous Pulse Width	4.6		5.3		5.6		7.0		9.8		ns
t _A Flip-Flop Clock Input Period	6.8		7.8		8.9		10.4		14.6		ns
f _{MAX} Flip-Flop (Latch) Clock Frequency (FO = 128)		109		101		92		80		48	MHz
Input Module Propagation Delays											
t _{I_{NYH}} Pad-to-Y HIGH		1.0		1.1		1.3		1.5		2.1	ns
t _{I_{NYL}} Pad-to-Y LOW		0.9		1.0		1.1		1.3		1.9	ns

Table 39 • A42MX09 Timing Characteristics (Nominal 3.3 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
CMOS Output Module Timing⁵											
t _{D LH}	Data-to-Pad HIGH		3.4		3.8		5.5		6.4		9.0 ns
t _{D HL}	Data-to-Pad LOW		4.1		4.5		4.2		5.0		7.0 ns
t _{ENZH}	Enable Pad Z to HIGH		3.7		4.1		4.6		5.5		7.6 ns
t _{ENZL}	Enable Pad Z to LOW		4.1		4.5		5.1		6.1		8.5 ns
t _{ENHZ}	Enable Pad HIGH to Z		6.9		7.6		8.6		10.2		14.2 ns
t _{ENLZ}	Enable Pad LOW to Z		7.5		8.3		9.4		11.1		15.5 ns
t _{GLH}	G-to-Pad HIGH		5.8		6.5		7.3		8.6		12.0 ns
t _{GHL}	G-to-Pad LOW		5.8		6.5		7.3		8.6		12.0 ns
t _{LSU}	I/O Latch Set-Up	0.7		0.8		0.9		1.0		1.4	ns
t _{LH}	I/O Latch Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{LCO}	I/O Latch Clock-to-Out (Pad-to-Pad), 64 Clock Loading		8.7		9.7		10.9		12.9		18.0 ns
t _{ACO}	Array Clock-to-Out (Pad-to-Pad), 64 Clock Loading		12.2		13.5		15.4		18.1		25.3 ns
d _{TLH}	Capacity Loading, LOW to HIGH	0.04		0.04		0.05		0.06		0.08	ns/pF
d _{THL}	Capacity Loading, HIGH to LOW	0.05		0.05		0.06		0.07		0.10	ns/pF

- For dual-module macros, use $t_{PD1} + t_{RD1} + t_{PDn}$, $t_{CO} + t_{RD1} + t_{PDn}$, or $t_{PD1} + t_{RD1} + t_{SUD}$, whichever is appropriate.
- Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual performance.
- Data applies to macros based on the S-module. Timing parameters for sequential macros constructed from C-modules can be obtained from the Timer utility.
- Set-up and hold timing parameters for the input buffer latch are defined with respect to the PAD and the D input. External setup/hold timing parameters must account for delay from an external PAD signal to the G inputs. Delay from an external PAD signal to the G input subtracts (adds) to the internal setup (hold) time.
- Delays based on 35 pF loading.

Table 40 • A42MX16 Timing Characteristics (Nominal 5.0 V Operation) (Worst-Case Commercial Conditions, VCCA = 4.75 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Propagation Delays¹											
t _{PD1}	Single Module	1.4		1.5		1.7		2.0		2.8	ns
t _{CO}	Sequential Clock-to-Q	1.4		1.6		1.8		2.1		3.0	ns
t _{GO}	Latch G-to-Q	1.4		1.5		1.7		2.0		2.8	ns
t _{RS}	Flip-Flop (Latch) Reset-to-Q	1.6		1.7		2.0		2.3		3.3	ns
Logic Module Predicted Routing Delays²											
t _{RD1}	FO = 1 Routing Delay	0.8		0.9		1.0		1.2		1.6	ns
t _{RD2}	FO = 2 Routing Delay	1.0		1.2		1.3		1.5		2.1	ns

Table 40 • A42MX16 Timing Characteristics (Nominal 5.0 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 4.75 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t _{RD3}	FO = 3 Routing Delay		1.3		1.4		1.6		1.9		2.7 ns
t _{RD4}	FO = 4 Routing Delay		1.6		1.7		2.0		2.3		3.2 ns
t _{RD8}	FO = 8 Routing Delay		2.6		2.9		3.2		3.8		5.3 ns
Logic Module Sequential Timing^{3,4}											
t _{SUD}	Flip-Flop (Latch) Data Input Set-Up		0.3		0.4		0.4		0.5		0.7 ns
t _{HD}	Flip-Flop (Latch) Data Input Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{SUENA}	Flip-Flop (Latch) Enable Set-Up	0.7		0.8		0.9		1.0		1.4	ns
t _{HENA}	Flip-Flop (Latch) Enable Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	3.4		3.8		4.3		5.0		7.1	ns
t _{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	4.5		5.0		5.6		6.6		9.2	ns
t _A	Flip-Flop Clock Input Period	6.8		7.6		8.6		10.1		14.1	ns
t _{INH}	Input Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{INSU}	Input Buffer Latch Set-Up	0.5		0.5		0.6		0.7		1.0	ns
t _{OUTH}	Output Buffer Latch Hold	0.0		0.0		0.0		0.0		0.0	ns
t _{OUTSU}	Output Buffer Latch Set-Up	0.5		0.5		0.6		0.7		1.0	ns
f _{MAX}	Flip-Flop (Latch) Clock Frequency	215		195		179		156		94	MHz
Input Module Propagation Delays											
t _{INYH}	Pad-to-Y HIGH		1.1		1.2		1.3		1.6		2.2 ns
t _{INYL}	Pad-to-Y LOW		0.8		0.9		1.0		1.2		1.7 ns
t _{INGH}	G to Y HIGH		1.4		1.6		1.8		2.1		2.9 ns
t _{INGL}	G to Y LOW		1.4		1.6		1.8		2.1		2.9 ns
Input Module Predicted Routing Delays²											
t _{IRD1}	FO = 1 Routing Delay		1.8		2.0		2.3		2.7		4.0 ns
t _{IRD2}	FO = 2 Routing Delay		2.1		2.3		2.6		3.1		4.3 ns
t _{IRD3}	FO = 3 Routing Delay		2.3		2.6		3.0		3.5		4.9 ns
t _{IRD4}	FO = 4 Routing Delay		2.6		3.0		3.3		3.9		5.4 ns
t _{IRD8}	FO = 8 Routing Delay		3.6		4.0		4.6		5.4		7.5 ns
Global Clock Network											
t _{CKH}	Input LOW to HIGH	FO = 32	2.6		2.9		3.3		3.9		5.4 ns
		FO = 384	2.9		3.2		3.6		4.3		6.0 ns
t _{CKL}	Input HIGH to LOW	FO = 32	3.8		4.2		4.8		5.6		7.8 ns
		FO = 384	4.5		5.0		5.6		6.6		9.2 ns
t _{PWH}	Minimum Pulse Width HIGH	FO = 32	3.2		3.5		4.0		4.7		6.6 ns
		FO = 384	3.7		4.1		4.6		5.4		7.6 ns

Table 41 • A42MX16 Timing Characteristics (Nominal 3.3 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 3.0 V, TJ = 70°C)

Parameter / Description	-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		Units
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Logic Module Sequential Timing^{3, 4}											
t _{SUD}	Flip-Flop (Latch) Data Input Set-Up	0.5	0.5	0.6	0.7	0.9					ns
t _{HD}	Flip-Flop (Latch) Data Input Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{SUENA}	Flip-Flop (Latch) Enable Set-Up	1.0	1.1	1.2	1.4	2.0					ns
t _{HENA}	Flip-Flop (Latch) Enable Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{WCLKA}	Flip-Flop (Latch) Clock Active Pulse Width	4.8	5.3	6.0	7.1	9.9					ns
t _{WASYN}	Flip-Flop (Latch) Asynchronous Pulse Width	6.2	6.9	7.9	9.2	12.9					ns
t _A	Flip-Flop Clock Input Period	9.5	10.6	12.0	14.1	19.8					ns
t _{IINH}	Input Buffer Latch Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{INSU}	Input Buffer Latch Set-Up	0.7	0.8	0.9	1.01	1.4					ns
t _{OUTH}	Output Buffer Latch Hold	0.0	0.0	0.0	0.0	0.0					ns
t _{OUTSU}	Output Buffer Latch Set-Up	0.7	0.8	0.89	1.01	1.4					ns
f _{MAX}	Flip-Flop (Latch) Clock Frequency	129	117	108	94	56	MHz				
Input Module Propagation Delays											
t _{IINYH}	Pad-to-Y HIGH	1.5	1.6	1.9	2.2	3.1	ns				
t _{IINYL}	Pad-to-Y LOW	1.1	1.3	1.4	1.7	2.4	ns				
t _{INGH}	G to Y HIGH	2.0	2.2	2.5	2.9	4.1	ns				
t _{INGL}	G to Y LOW	2.0	2.2	2.5	2.9	4.1	ns				
Input Module Predicted Routing Delays²											
t _{IRD1}	FO = 1 Routing Delay	2.6	2.9	3.2	3.8	5.3	ns				
t _{IRD2}	FO = 2 Routing Delay	2.9	3.2	3.7	4.3	6.1	ns				
t _{IRD3}	FO = 3 Routing Delay	3.3	3.6	4.1	4.9	6.8	ns				
t _{IRD4}	FO = 4 Routing Delay	3.6	4.0	4.6	5.4	7.6	ns				
t _{IRD8}	FO = 8 Routing Delay	5.1	5.6	6.4	7.5	10.5	ns				
Global Clock Network											
t _{CKH}	Input LOW to HIGH	FO = 32	4.4	4.8	5.5	6.5	9.0	ns			
		FO = 384	4.8	5.3	6.0	7.1	9.9	ns			
t _{CKL}	Input HIGH to LOW	FO = 32	5.3	5.9	6.7	7.8	11.0	ns			
		FO = 384	6.2	6.9	7.9	9.2	12.9	ns			
t _{PWH}	Minimum Pulse Width HIGH	FO = 32	5.7	6.3	7.1	8.4	11.8	ns			
		FO = 384	6.6	7.4	8.3	9.8	13.7	ns			

Table 43 • A42MX24 Timing Characteristics (Nominal 3.3 V Operation) (continued)(Worst-Case Commercial Conditions, VCCA = 3.0 V, TJ = 70°C)

Parameter / Description		-3 Speed		-2 Speed		-1 Speed		Std Speed		-F Speed		
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
Input Module Predicted Routing Delays²												
t _{IRD1}	FO = 1 Routing Delay			2.6		2.9		3.2		3.8		5.3 ns
t _{IRD2}	FO = 2 Routing Delay			2.9		3.2		3.6		4.3		6.0 ns
t _{IRD3}	FO = 3 Routing Delay			3.2		3.6		4.0		4.8		6.6 ns
t _{IRD4}	FO = 4 Routing Delay			3.5		3.9		4.4		5.2		7.3 ns
t _{IRD8}	FO = 8 Routing Delay			4.8		5.3		6.1		7.1		10.0 ns
Global Clock Network												
t _{CKH}	Input LOW to HIGH	FO = 32		4.4		4.8		5.5		6.5		9.1 ns
		FO = 486		4.8		5.3		6.0		7.1		10.0 ns
t _{CKL}	Input HIGH to LOW	FO = 32		5.1		5.7		6.4		7.6		10.6 ns
		FO = 486		6.0		6.6		7.5		8.8		12.4 ns
t _{PWH}	Minimum Pulse Width HIGH	FO = 32	3.0		3.3		3.8		4.5		6.3	ns
		FO = 486	3.3		3.7		4.2		4.9		6.9	ns
t _{PWL}	Minimum Pulse Width LOW	FO = 32	3.0		3.4		3.8		4.5		6.3	ns
		FO = 486	3.3		3.7		4.2		4.9		6.9	ns
t _{CKSW}	Maximum Skew	FO = 32		0.8		0.8		1.0		1.1		1.6 ns
		FO = 486		0.8		0.8		1.0		1.1		1.6 ns
t _{SUEXT}	Input Latch External Set-Up	FO = 32	0.0		0.0		0.0		0.0		0.0	ns
		FO = 486	0.0		0.0		0.0		0.0		0.0	ns
TTL Output Module Timing⁵												
t _{DLH}	Data-to-Pad HIGH			3.4		3.8		4.3		5.0		7.1 ns
t _{DHL}	Data-to-Pad LOW			4.0		4.4		5.0		5.9		8.3 ns
t _{ENZH}	Enable Pad Z to HIGH			3.6		4.0		4.5		5.3		7.4 ns
t _{ENZL}	Enable Pad Z to LOW			3.9		4.4		5.0		5.8		8.2 ns
t _{ENHZ}	Enable Pad HIGH to Z			7.2		8.0		9.1		10.7		14.9 ns
t _{ENLZ}	Enable Pad LOW to Z			6.7		7.5		8.5		9.9		13.9 ns
t _{GLH}	G-to-Pad HIGH			4.8		5.3		6.0		7.2		10.0 ns
t _{GHL}	G-to-Pad LOW			4.8		5.3		6.0		7.2		10.0 ns
t _{LSU}	I/O Latch Output Set-Up			0.7		0.7		0.8		1.0		1.4 ns

Table 52 • PQ160

PQ160	Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function
	21	CLKA, I/O	CLKA, I/O	CLKA, I/O
	22	I/O	I/O	I/O
	23	PRA, I/O	PRA, I/O	PRA, I/O
	24	NC	I/O	WD, I/O
	25	I/O	I/O	WD, I/O
	26	I/O	I/O	I/O
	27	I/O	I/O	I/O
	28	NC	I/O	I/O
	29	I/O	I/O	WD, I/O
	30	GND	GND	GND
	31	NC	I/O	WD, I/O
	32	I/O	I/O	I/O
	33	I/O	I/O	I/O
	34	I/O	I/O	I/O
	35	NC	VCCI	VCCI
	36	I/O	I/O	WD, I/O
	37	I/O	I/O	WD, I/O
	38	SDI, I/O	SDI, I/O	SDI, I/O
	39	I/O	I/O	I/O
	40	GND	GND	GND
	41	I/O	I/O	I/O
	42	I/O	I/O	I/O
	43	I/O	I/O	I/O
	44	GND	GND	GND
	45	I/O	I/O	I/O
	46	I/O	I/O	I/O
	47	I/O	I/O	I/O
	48	I/O	I/O	I/O
	49	GND	GND	GND
	50	I/O	I/O	I/O
	51	I/O	I/O	I/O
	52	NC	I/O	I/O
	53	I/O	I/O	I/O
	54	NC	VCCA	VCCA
	55	I/O	I/O	I/O
	56	I/O	I/O	I/O
	57	VCCA	VCCA	VCCA

Table 53 • PQ208

PQ208	Pin Number	A42MX16 Function	A42MX24 Function	A42MX36 Function
	132	VCCI	VCCI	VCCI
	133	VCCA	VCCA	VCCA
	134	I/O	I/O	I/O
	135	I/O	I/O	I/O
	136	VCCA	VCCA	VCCA
	137	I/O	I/O	I/O
	138	I/O	I/O	I/O
	139	I/O	I/O	I/O
	140	I/O	I/O	I/O
	141	NC	I/O	I/O
	142	I/O	I/O	I/O
	143	I/O	I/O	I/O
	144	I/O	I/O	I/O
	145	I/O	I/O	I/O
	146	NC	I/O	I/O
	147	NC	I/O	I/O
	148	NC	I/O	I/O
	149	NC	I/O	I/O
	150	GND	GND	GND
	151	I/O	I/O	I/O
	152	I/O	I/O	I/O
	153	I/O	I/O	I/O
	154	I/O	I/O	I/O
	155	I/O	I/O	I/O
	156	I/O	I/O	I/O
	157	GND	GND	GND
	158	I/O	I/O	I/O
	159	SDI, I/O	SDI, I/O	SDI, I/O
	160	I/O	I/O	I/O
	161	I/O	WD, I/O	WD, I/O
	162	I/O	WD, I/O	WD, I/O
	163	I/O	I/O	I/O
	164	VCCI	VCCI	VCCI
	165	NC	I/O	I/O
	166	NC	I/O	I/O
	167	I/O	I/O	I/O
	168	I/O	WD, I/O	WD, I/O

Table 54 • PQ240

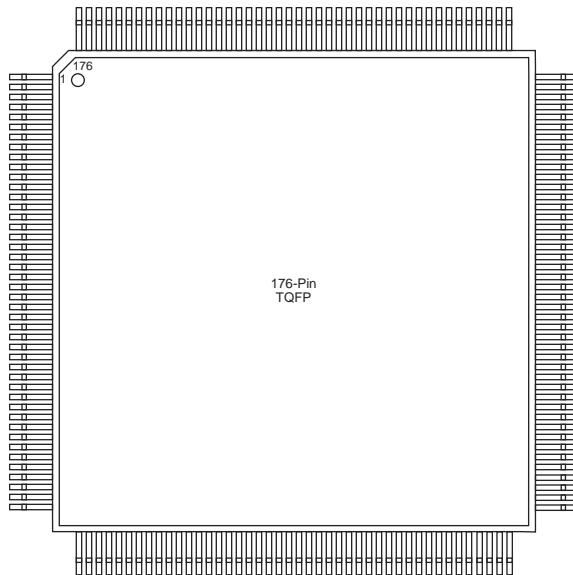
PQ240	
Pin Number	A42MX36 Function
200	I/O
201	I/O
202	I/O
203	I/O
204	I/O
205	I/O
206	VCCA
207	I/O
208	I/O
209	VCCA
210	VCCI
211	I/O
212	I/O
213	I/O
214	I/O
215	I/O
216	I/O
217	I/O
218	I/O
219	VCCA
220	I/O
221	I/O
222	I/O
223	I/O
224	I/O
225	I/O
226	I/O
227	VCCI
228	I/O
229	I/O
230	I/O
231	I/O
232	I/O
233	I/O
234	I/O
235	I/O
236	I/O

Table 55 • VQ80

VQ80		
Pin Number	A40MX02 Function	A40MX04 Function
49	I/O	I/O
50	CLK, I/O	CLK, I/O
51	I/O	I/O
52	MODE	MODE
53	VCC	VCC
54	NC	I/O
55	NC	I/O
56	NC	I/O
57	SDI, I/O	SDI, I/O
58	DCLK, I/O	DCLK, I/O
59	PRA, I/O	PRA, I/O
60	NC	NC
61	PRB, I/O	PRB, I/O
62	I/O	I/O
63	I/O	I/O
64	I/O	I/O
65	I/O	I/O
66	I/O	I/O
67	I/O	I/O
68	GND	GND
69	I/O	I/O
70	I/O	I/O
71	I/O	I/O
72	I/O	I/O
73	I/O	I/O
74	VCC	VCC
75	I/O	I/O
76	I/O	I/O
77	I/O	I/O
78	I/O	I/O
79	I/O	I/O
80	I/O	I/O

Table 56 • VQ100

VQ100		
Pin Number	A42MX09 Function	A42MX16 Function
93	I/O	I/O
94	GND	GND
95	I/O	I/O
96	I/O	I/O
97	I/O	I/O
98	I/O	I/O
99	I/O	I/O
100	DCLK, I/O	DCLK, I/O

Figure 48 • TQ176**Table 57 • TQ176**

TQ176			
Pin Number	A42MX09 Function	A42MX16 Function	A42MX24 Function
1	GND	GND	GND
2	MODE	MODE	MODE
3	I/O	I/O	I/O
4	I/O	I/O	I/O
5	I/O	I/O	I/O
6	I/O	I/O	I/O
7	I/O	I/O	I/O
8	NC	NC	I/O
9	I/O	I/O	I/O

Table 59 • CQ256

CQ256	
Pin Number	A42MX36 Function
133	I/O
134	I/O
135	I/O
136	I/O
137	I/O
138	I/O
139	GND
140	I/O
141	I/O
142	I/O
143	I/O
144	I/O
145	I/O
146	I/O
147	I/O
148	I/O
149	I/O
150	I/O
151	I/O
152	I/O
153	I/O
154	I/O
155	VCCA
156	I/O
157	I/O
158	VCCA
159	VCCI
160	GND
161	I/O
162	I/O
163	I/O
164	I/O
165	GND
166	I/O
167	I/O
168	I/O
169	I/O

Table 60 • BG272

BG272	
Pin Number	A42MX36 Function
J9	GND
J10	GND
J11	GND
J12	GND
J17	VCCA
J18	I/O
J19	I/O
J20	I/O
K1	I/O
K2	I/O
K3	I/O
K4	VCCI
K9	GND
K10	GND
K11	GND
K12	GND
K17	I/O
K18	VCCA
K19	VCCA
K20	LP
L1	I/O
L2	I/O
L3	VCCA
L4	VCCA
L9	GND
L10	GND
L11	GND
L12	GND
L17	VCCI
L18	I/O
L19	I/O
L20	TCK, I/O
M1	I/O
M2	I/O
M3	I/O
M4	VCCI
M9	GND

Figure 53 • CQ172**Table 62 • CQ172**

CQ172	
Pin Number	A42MX16 Function
1	MODE
2	I/O
3	I/O
4	I/O
5	I/O
6	I/O
7	GND
8	I/O
9	I/O
10	I/O
11	I/O
12	VCC
13	I/O
14	I/O
15	I/O
16	I/O
17	GND
18	I/O
19	I/O
20	I/O